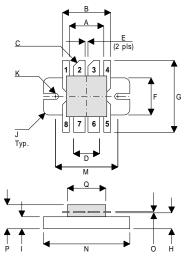
TetraFET

D1217UK



ROHS COMPLIANT METAL GATE RF SILICON FET

MECHANICAL DATA





PIN 1 SOURCE (COMMON) PIN 2 DRAIN 1 PIN 3 DRAIN 2 PIN 4 SOURCE (COMMON) PIN 5 SOURCE (COMMON) PIN 6 GATE 2

PIN 7

GATE 1		P	IN 8 SO	URCE (C	COMMON)
DIM	mm	Tol.	Inches	Tol.	
А	9.14	0.13	0.360	0.005	
В	12.70	0.13	0.500	0.005	
С	45°	5°	45°	5°	
D	6.86	0.13	0.270	0.005	
Е	0.76	0.13	0.030	0.005	
F	9.78	0.13	0.385	0.005	
G	19.05	0.25	0.750	0.010	
Н	4.19	0.13	0.165	0.005	
Ι	3.17	0.13	0.125	0.005	
L	1.52R	0.13	0.060R	0.005	
Κ	1.65R	0.13	0.065R	0.005	
Μ	16.51	0.13	0.650	0.005	
Ν	22.86	0.13	0.900	0.005	
0	0.13	0.02	0.005	0.001	
Ρ	6.35	0.64	0.250	0.025	
Q	10.77	0.13	0.424	0.005	

GOLD METALLISED MULTI-PURPOSE SILICON DMOS RF FET 40W - 12.5V - 500MHz **PUSH-PULL**

FEATURES

- SIMPLIFIED AMPLIFIER DESIGN
- SUITABLE FOR BROAD BAND APPLICATIONS
- LOW C_{rss}
- SIMPLE BIAS CIRCUITS
- LOW NOISE
- HIGH GAIN 10 dB MINIMUM

APPLICATIONS

 HF/VHF/UHF COMMUNICATIONS from 1 MHz to 500 MHz

ABSOLUTE MAXIMUM RATINGS ($T_{case} = 25$ °C unless otherwise stated)

P _D	Power Dissipation	175W
BV _{DSS}	Drain – Source Breakdown Voltage*	40V
BV _{GSS}	Gate – Source Breakdown Voltage*	±20V
I _{D(sat)}	Drain Current*	20A
T _{stg} ′	Storage Temperature	–65 to 150℃
Tj	Maximum Operating Junction Temperature	200°C

^{*} Per side

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ELECTRICAL CHARACTERISTICS (T_{case} = 25°C unless otherwise stated)

	Parameter	Test Co	Min.	Тур.	Max.	Unit		
	PER SIDE							
BV	Drain–Source	V _{GS} = 0	I _D = 100mA	40			V	
BV _{DSS}	Breakdown Voltage	VGS – 0	ID = 1001114	40			v	
	Zero Gate Voltage	\/ _ 12 5\/				2	mA	
IDSS	Drain Current	$V_{DS} = 12.5V$ $V_{GS} = 0$				2	IIIA	
I _{GSS}	Gate Leakage Current	V _{GS} = 20V	$V_{DS} = 0$			1	μΑ	
V _{GS(th)}	Gate Threshold Voltage*	I _D = 10mA	$V_{DS} = V_{GS}$	1		7	V	
9 _{fs}	Forward Transconductance*	V _{DS} = 10V	I _D = 2A	1.6			S	
		TOTAL	DEVICE					
G _{PS}	Common Source Power Gain	P _O = 40W		10			dB	
η	Drain Efficiency	V _{DS} = 12.5V	I _{DQ} = 1.6A	50			%	
VSWR	Load Mismatch Tolerance	f = 400MHz		20:1			_	
PER SIDE								
C _{iss}	Input Capacitance	$V_{DS} = 0V V_{GS}$	$_{\rm S} = -5V$ f = 1MHz			120	pF	
C _{oss}	Output Capacitance	$V_{DS} = 12.5V V_{GS}$	f = 0 f = 1MHz			80	pF	
C _{rss}	Reverse Transfer Capacitance	$V_{DS} = 12.5V V_{GS}$	f = 0 f = 1MHz			8	pF	

* Pulse Test: Pulse Duration = 300 μs , Duty Cycle $\leq 2\%$

HAZARDOUS MATERIAL WARNING

The ceramic portion of the device between leads and metal flange is beryllium oxide. Beryllium oxide dust is highly toxic and care must be taken during handling and mounting to avoid damage to this area.

THESE DEVICES MUST NEVER BE THROWN AWAY WITH GENERAL INDUSTRIAL OR DOMESTIC WASTE.

THERMAL DATA

R _{THj-case}	Thermal Resistance Junction – Case	Max. 1.0℃ / W
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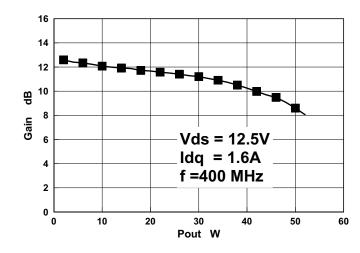
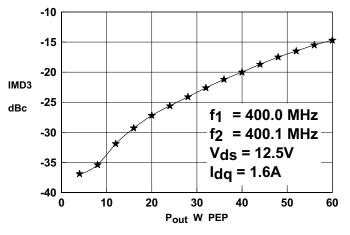


Figure 1- Gain vs. Power Output





Typical S Parameters

 $V_{DS} = 12.5V, I_{DQ} = 0.4A$ ļ # MHZ S MA R 50

			0					
!Freq !MHz	S11 mag	ang	S21 mag	ang	S12 mag	ang	S22 mag	ang
70 100 250 300 350 400 450 550 600 650 700	0.71 0.75 0.81 0.85 0.88 0.90 0.91 0.92 0.93 0.93 0.94 0.95 0.95 0.95	-151.2 -156.2 -162.7 -167.4 -171.0 -173.9 -175.1 -177.9 -179.7 178.1 175.9 174.2 172.2 170.9	9.5 6.1 3.7 2.4 1.7 1.0 0.8 0.7 0.6 0.5 0.4 0.3 0.2	73.1 62.2 50.4 44.0 36.6 34.5 26.0 23.4 17.6 13.3 8.2 2.5 8.9 19.2	0.019 0.016 0.012 0.009 0.008 0.009 0.010 0.014 0.017 0.021 0.023 0.028 0.029 0.034	-9.1 -13.2 -12.8 0.4 20.8 49.0 60.6 70.2 75.0 77.9 78.5 77.1 80.6 76.8	0.77 0.79 0.83 0.86 0.88 0.90 0.91 0.92 0.93 0.93 0.94 0.95 0.95	-163.9 -166.0 -169.7 -172.8 -175.3 -176.6 -178.7 -180.0 178.6 176.8 176.8 175.4 174.4 172.9 171.8

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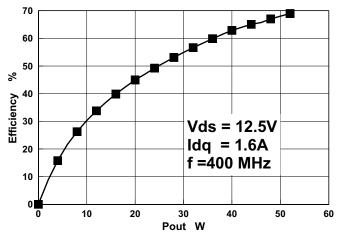


Figure 2 - Efficiency vs Power Output

OPTIMUM SOURCE AND LOAD IMPEDANCE

Frequency	Z _S	ZL		
MHz	Ω	Ω		
400	1.5 + j1.2	1.9 - j1.1		

Semelab plc. Telephone +44(0)1455 556565. Fax +44(0)1455 552612. E-mail: sales@semelab.co.uk

Website: http://www.semelab.co.uk



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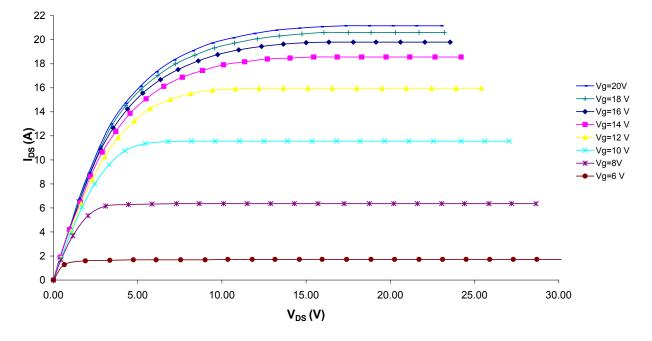
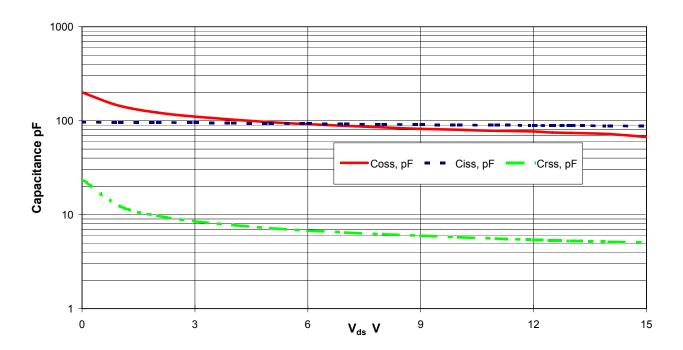


Figure 4 – Typical IV Characteristics.

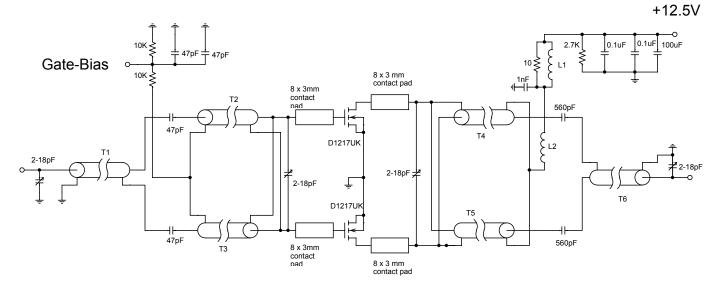




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D1217UK TEST FIXTURE

- T1 50 Ohm semi-rigid coax 0.034" dia, 7cm long
- T2,3 25 Ohm semi-rigid coax 0.070" dia, 10cm long on Siemens B62152A1X1 ferrite core
- T4,5 25 Ohm semi-rigid coax 0.070" dia, 10cm long
- T6 50 Ohm semi-rigid coax 0.034" dia, 7cm long
- L1 2.5 turns 1mm dia enamelled copper wire on Siemens B62152A1X1 ferrite core
- L2 6 turns 2 mm dia enamelled copper wire, 3.5mm internal diameter

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